



# 0.95-1.65um InGaAs Avalanche Photodiode in Ceramic Package APD-CS916200

Data Sheet

## Description

The APD-CS916200 is a planar InGaAs avalanche photodiode (APD) housed in a compact and reliable 6CLCC ceramic package. It provides high responsivity across 0.95–1.65  $\mu\text{m}$ , making it well-suited for near-infrared and short-wave infrared (SWIR) detection. With a  $\geq 700$  MHz 3dB bandwidth, low leakage current, and low noise characteristics, the device delivers excellent performance in demanding optical applications such as LIDAR, optical communication, and precision sensing.

## Features

- InGaAs avalanche photodiode (APD) in 6CLCC ceramic package
- Highly reliable planar device
- High responsivity in 0.95–1.65  $\mu\text{m}$
- $\geq 700$  MHz 3dB bandwidth
- Low leakage current and noise
- Low stray absorption

## Applications

- Light Detection and Ranging (LIDAR)
- Fiber optic communication & testing
- Spectral analysis
- Optical coherence tomography (OCT)
- Single-photodiode SWIR cameras
- Covert IR sensing

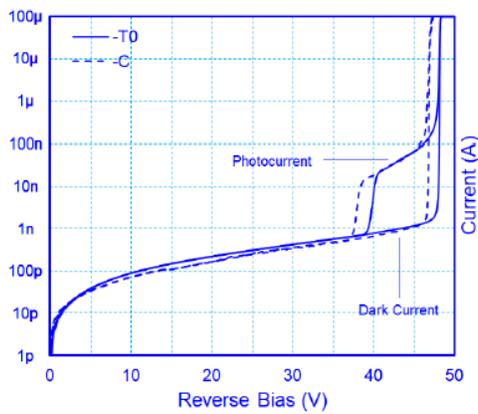
## Specifications

Absolute Maximum Ratings				
Parameters	Symbol	Rating	Unit	Conditions
Reverse current	$I_R$	1	mA	
Forward current	$I_F$	5	$\mu\text{m}$	
Operation temperature	$T_{op}$	-40 to 85	$^{\circ}\text{C}$	
Storage temperature	$T_{stg}$	-40 to 85	$^{\circ}\text{C}$	

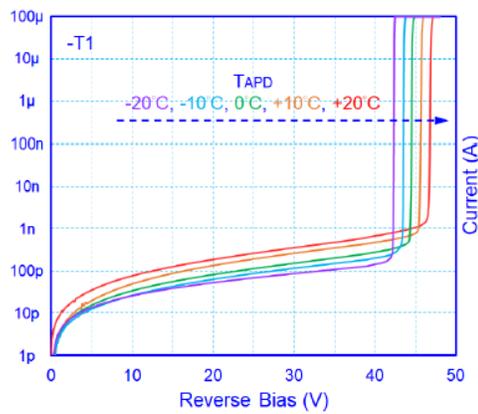
Electro-Optical Characteristics ( $T_a=23^{\circ}\text{C}$ )						
Parameters	Symbol	Min.	Typ.	Max.	Unit	Conditions
Wavelength spectral range	$\lambda$	0.95		1.65	$\mu\text{m}$	
Aperture size			200		$\mu\text{m}$	
Dark current	$I_D$		5	50	nA	M=10
Operating voltage	$V_{op}$	32		50	V	M=10
Breakdown voltage	$V_{BD}$	35		55	V	$I_{BD}=100\mu\text{A}$
Capacitance	$C_J$	-	2.5	3.0	pF	M=10, f=1MHz
Responsivity	$I_L$	8	9		A/W	M=10, $\lambda=1.55\mu\text{m}$
Useable gain		10	20	-		$\lambda=1.55\mu\text{m}$
3dB bandwidth ( $f_{3dB}$ )		0.7	0.85		GHz	M=10, $\lambda=1.55\mu\text{m}$
Spectral noise current		-	0.5	1.5	$\text{pA}/\sqrt{\text{Hz}}$	M=10, $\Delta f=1\text{kHz}$
Temperature coefficient of $V_{BD}$		-	0.10	0.15	$\text{V}/^{\circ}\text{C}$	

Typical Characteristics

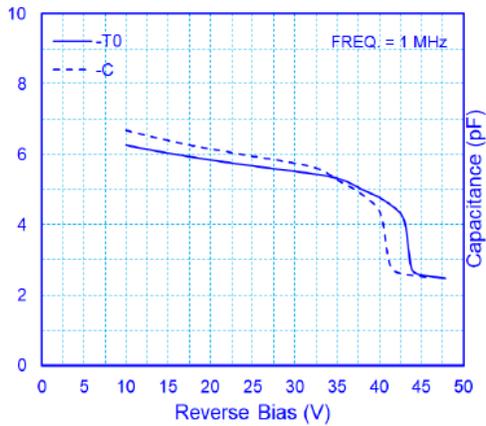
Dark- / Photo-Current



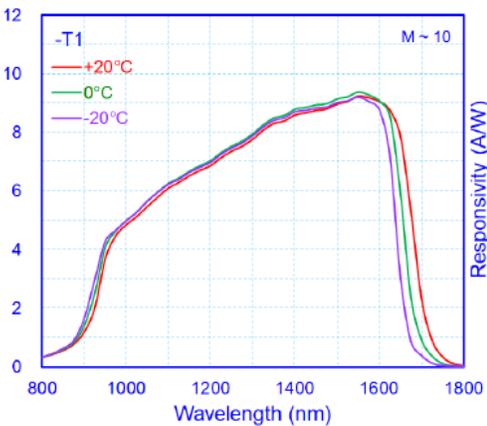
Dark Current



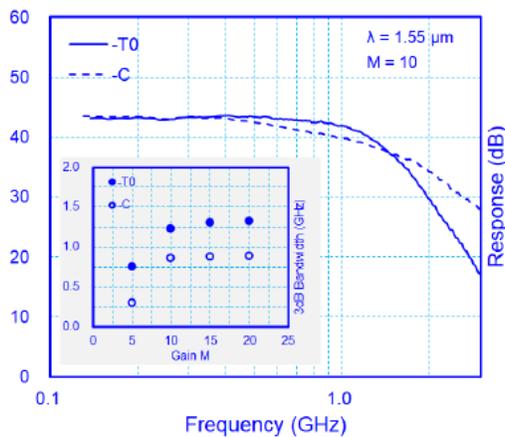
Dark Capacitance



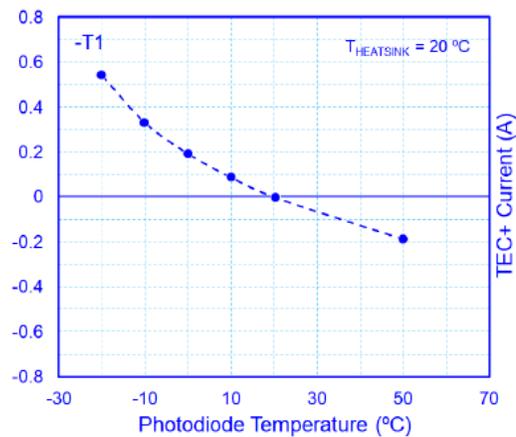
Responsivity Spectrum



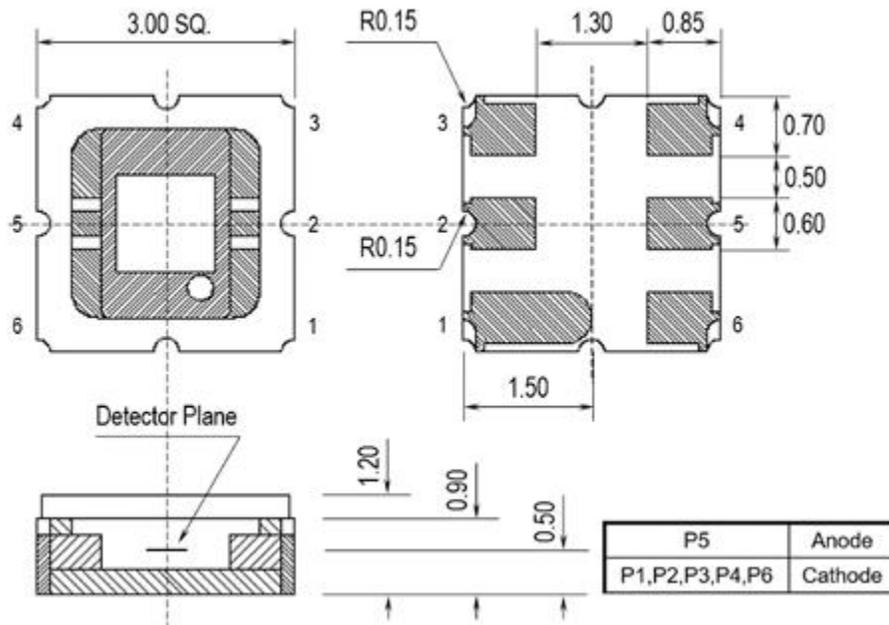
Frequency Response



TEC Performance



Outline Dimensions (unit: mm)



Note: Specifications are subject to change without notice.